NSN 5961-01-361-4376

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-361-4376 **Inclosure Material:** Metal **Overall Length:** 1.237 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-4 **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Features Provided:** Reverse polarity **Overall Width Across Flats:** Between 0.420 inches and 0.430 inches **Thread Size:** 0.190 inches **Criticality Code Justification:** Cbbl **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 20.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 banana plug and 2 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** Fiig:

No

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